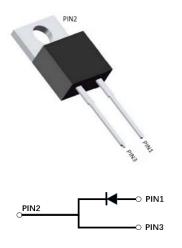






# **Silicon Carbide Schottky Diode**

$V_{RRM}$	1200V
I <sub>F(135°C)</sub>	15A
Q <sub>C</sub>	58nC



#### **Features**

- Positive temperature coefficient
- Temperature-independent switching
- Maximum working temperature at 175 °C
- Unipolar devices and zero reverse recovery current
- Zero forward recovery current
- Essentially no switching losses
- Reduction of heat sink requirements
- High-frequency operation
- Reduction of EMI

#### **Typical Applications**

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

#### **Mechanical Data**

Package: TO-220AC
 Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant, halogen-free

• Terminals: Tin plated leads

• Polarity: As marked

### ■Maximum Ratings (T<sub>C</sub>=25°C Unless otherwise specified)

PARAMTETER	SYMBOL	UNIT	VALUE
Device marking code			D112010PGH
Reverse voltage (Repetitive peak) @ T <sub>j</sub> =25°C	$V_{RRM}$	V	1200
Reverse voltage (Surge peak) @ T <sub>j</sub> =25°C	$V_{RSM}$	V	1200
Reverse voltage (DC) @ T <sub>j</sub> =25°C	$V_{DC}$	V	1200
Continuous forward current @ T <sub>c</sub> =25°C			31.5
Continuous forward current @ T <sub>c</sub> =135°C	I <sub>F</sub>	Α	15
Continuous forward current @ T <sub>C</sub> =155°C			10
Non-repetitive peak forward surge current @ T <sub>C</sub> =25°C, tp=10ms, Half Sine Wave	I <sub>FSM</sub>	А	90
Power Dissipation@ T <sub>C</sub> =25°C	P <sub>TOT</sub>	W	153
Power Dissipation@ T <sub>C</sub> =110°C	Гтот		66
i²t Value@ T <sub>C</sub> =25°C ,tp=10ms	∫ i²dt	A <sup>2</sup> S	40.5
Operating junction and Storage temperature range	$T_j$ , $T_stg$	°C	-55 to +175



### **■**Electrical Characteristics

PARAMTETER	SYMBOL	UNIT	TEST CONDITIONS	Тур.	Max.
Forward voltage drop	V <sub>F</sub>	V	I <sub>F</sub> =10A, T <sub>j</sub> =25°C	1.38	1.55
			I <sub>F</sub> =10A, T <sub>j</sub> =175°C	2	-
Reverse leakage current	I <sub>R</sub>	μΑ	V <sub>R</sub> =1200V, T <sub>j</sub> =25°C	0.5	20
			V <sub>R</sub> =1200V, T <sub>j</sub> =175°C	8	-
Total capacitive charge	Q <sub>C</sub>	nC	$\begin{array}{c} V_R = 800V, \ T_j = 25^{\circ}C \ , \\ Q_C = \int_0^{VR} C(V) dV \end{array}$	58	-
Total capacitance	С	pF	V <sub>R</sub> =0V, f=1MHZ	813	-
			V <sub>R</sub> =400V, f=1MHZ	54	-
			V <sub>R</sub> =800V, f=1MHZ	40	-
Capacitance Stored Energy	Ec	μJ	V <sub>R</sub> =800V	15	-

## **■Thermal Characteristics** $(T_a=25$ $^{\circ}$ C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Thermal resistance	$R_{\theta J-C}$	°C W	0.98

## **■**Typical Characteristics

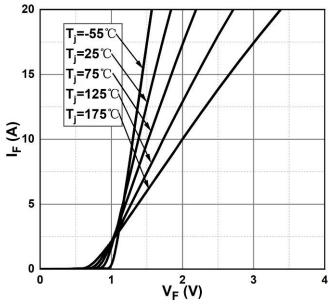


Figure 1. Forward Characteristics

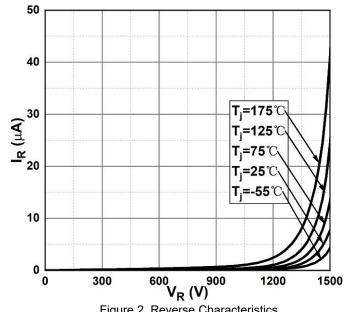
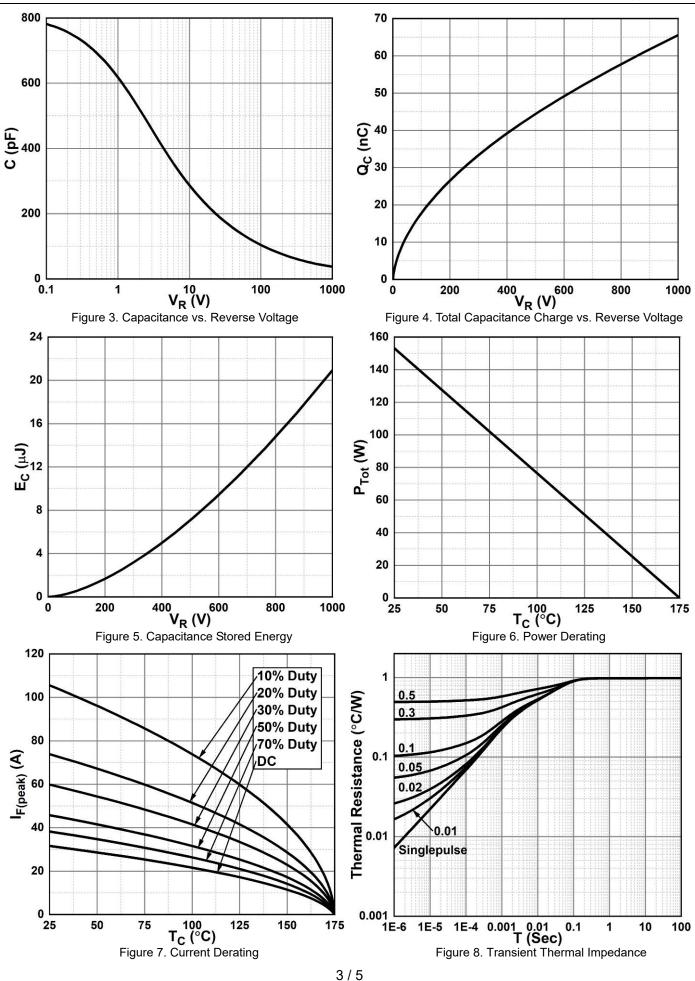


Figure 2. Reverse Characteristics

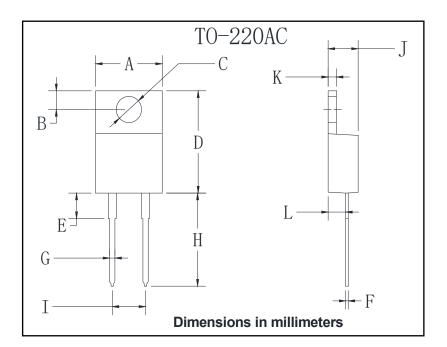








### **■**Outline Dimensions



TO-220AC				
Dim	Min	Max		
Α	9.95	10.35		
В	2.55	2.95		
С	3.75	4.05		
D	14.95	15.25		
Е	3.75	4.25		
F	0.26	0.5		
G	0.68	0.94		
Н	13.3	13.9		
I	4.86	5.26		
J	4.38	4.78		
K	1.14	1.4		
L	2.37	2.79		



## **YJD112010PGH**



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